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APPLICATION NO.	F	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/683,486	09/683,486 01/07/2002		Andres Bryant	BUR920010086 2808	
30607	7590	04/23/2003			
	-	EN & WATTS LL	EXAMINER		
MESA, AZ		Y DRIVE, #101		GEBREMARIA	M, SAMUEL A
				ART UNIT	PAPER NUMBER
				2811	
			DATE MAILED: 04/23/2003		

Please find below and/or attached an Office communication concerning this application or proceeding.

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	A	application No.	Applicant(s)	X,
Office Astrono		09/683,486	BRYANT ET AL.	
Office Action Summa	ery E	xaminer	Art Unit	
		amuel A Gebremariam	2811	
Peri d for Reply	mmunication appear	rs on the cover sheet wit	h the correspondence address	i
A SHORTENED STATUTORY PER THE MAILING DATE OF THIS COM - Extensions of time may be available under the pr after SIX (6) MONTHS from the mailing date of th - If the period for reply specified above is less than - If NO period for reply is specified above, the max - Failure to reply within the set or extended period - Any reply received by the Office later than three r earned patent term adjustment. See 37 CFR 1.76 Status	IMUNICATION. ovisions of 37 CFR 1.136(a) nis communication. thirty (30) days, a reply with intry metaturory period will al for reply will, by statute, cau nonths after the mailing date.). In no event, however, may a re nin the statutory minimum of thirty pply and will expire SIX (6) MONT se the application to become ABA	ply be timely filed (30) days will be considered timely. HS from the mailing date of this communi	cation.
1) Responsive to communication	n(s) filed on <u>21 Feb</u>	ruary 2003 .		
2a)☐ This action is FINAL .		ction is non-final.		
3) Since this application is in conclused in accordance with the Disposition of Claims	ndition for allowance	e except for formal matte	ers, prosecution as to the med	rits is
4)⊠ Claim(s) <u>12-25</u> is/are pending	in the application.			
4a) Of the above claim(s)	_ is/are withdrawn f	from consideration.		
5)⊠ Claim(s) <u>21-25</u> is/are allowed.				
6)⊠ Claim(s) <u>12-16 and 18-20</u> is/ar	e rejected.			
7)⊠ Claim(s) <u>17 and 19</u> is/are objec	cted to.			
8) Claim(s) are subject to i		ection requirement.		
Application Papers		-		
9)☐ The specification is objected to	by the Examiner.			
10)☐ The drawing(s) filed on is	s/are: a)∏ accepted	or b)☐ objected to by the	e Examiner.	
Applicant may not request that a			• •	
11)☐ The proposed drawing correctio			approved by the Examiner.	
If approved, corrected drawings a				
12) The oath or declaration is object	_	ner.		
Priority under 35 U.S.C. §§ 119 and 12				
13) Acknowledgment is made of a		ority under 35 U.S.C. §	119(a)-(d) or (f).	
a) ☐ All b) ☐ Some * c) ☐ None	e of:			
1. Certified copies of the pri	iority documents ha	ve been received.		
2. Certified copies of the pri	iority documents ha	ve been received in App	olication No	
3. Copies of the certified co application from the I* See the attached detailed Office	nternational Bureau	(PCT Rule 17.2(a)).	_	
14)☐ Acknowledgment is made of a cla				nation)
a) The translation of the foreig				alion).
15) Acknowledgment is made of a cl	aim for domestic pri	iority under 35 U.S.C. &	n received. § 120 and/or 121.	
Attachment(s)	•			
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Reviols Information Disclosure Statement(s) (PTO-14) 	iew (PTO-948) I49) Paper No(s) <u>2</u> .		mmary (PTO-413) Paper No(s) ormal Patent Application (PTO-152)	
S. Patent and Trademark Office PTO-326 (Rev. 04-01)	Office Action :	Summary	Part of Paper	No 5

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DETAILED ACTION

Election/Restrictions

1. Applicant's election without traverse of group II, claims 12-25 drawn to a semiconductor device in Paper No. 4 is acknowledged.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

3. Claims 12, 14, 15, 18 and 20 are rejected under 35 U.S.C. 102(b) as being anticipated by Bryant et al., US patent No. 6,159,807.

Regarding claim 12, Bryant teaches (figs. 1, 3 and 4) a transistor comprising: a) a transistor body (42) formed on a substrate (12), the transistor body having a first vertical edge (the edge near the left trench (50)) and a second vertical edge (the edge near the right trench (50)), b) a gate structure (56) adjacent the transistor body first vertical edge (portion of the gate on the left hand side the transistor); c) a body contact structure (16) adjacent the transistor body second vertical edge and aligned with the gate, d) a bridge (72) over the body (42), the gate (56), and the body contact (16), electrically connecting the gate and the body contact; and e) source (18) and drain (20) regions in the body on opposite ends of the body.

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Regarding claim 14, Bryant teaches (fig. 3a) the entire claimed structure of claim 12 above including the gate structure comprises n-type material (col. 5, lines 36-38) and wherein the body contact structure comprises p-type (col. 5, lines 58-63) material.

Regarding claim 15, Bryant teaches (fig. 3a, col. 3, lines 58-63) the entire claimed structure of claim 12 above including the transistor body (42) comprises a portion of silicon of the silicon-on-insulator layer.

Regarding claim 18, Bryant teaches (fig. 1) the entire claimed structure of claim 12 above including the transistor body (42) comprises source (20) and drain (18) implants into the transistor body, the implants aligned with the edges of the body contact.

Regarding claim 20, Bryant teaches (fig. 3a) the entire claimed structure of claim 12 above including the transistor body first edge (the edge near the left trench (50)) is opposite the transistor body second edge (the edge near the right trench (50)) and wherein the transistor body first edge and transistor body second edge are substantially perpendicular to a top surface of the substrate (12).

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 13 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Bryant.

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Regarding claim 13, Bryant teaches substantially the entire claimed structure of claim 12 above except explicitly stating that the gate structure comprises p-type material and wherein the body contact structure comprises n-type material.

Bryant teaches gate structure comprising n-type material (col. 5, lines 36-38) and wherein the body contact structure comprising p-type (col. 5, lines 58-63) material.

Furthermore parameters such as doping type and concentration in the art of semiconductor manufacturing process are subject to routine experimentation and optimization to achieve the desired device characteristics during fabrication.

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to adjust the doping type as claimed in order to form a CMOS device.

Regarding claim 16, Bryant teaches substantially the entire claimed structure of claim 12 above except explicitly stating the thickness of the transistor body between the gate structure and the body contact structure is less than one-third of the length of the gate structure.

Parameters such as thickness and width in the art of semiconductor manufacturing process are subject to routine experimentation and optimization to achieve the desired device characteristics during fabrication.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to adjust the thickness of the transistor body as claimed in order to form a CMOS device.

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Allowable Subj ct Matt r

6. Claims 17 and 19 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Allowance

7. Claims 21-25 are allowed.

Reason for allowance

8. The following is a statement of reasons for the indication of allowable subject matter: prior art of record does not anticipate or render obvious the limitation of "a body contact native oxide layer formed on the transistor body second edge; a body contact structure formed on the body contact native oxide layer aligned to the gate structure and adjacent to the transistor body second edge" for a transistor body.

Conclusion

9. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Reference A is cited as being related to transistor structure.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Samuel Admassu Gebremariam whose telephone number is 703 305 1913. The examiner can normally be reached on Monday-Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on 703-308-2772. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7722 for After Final communications.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

Samuel Admassu Gebremariam April 18, 2003

Tim Sole